

## 74ACQ573 • 74ACTQ573 Quiet Series™ Octal Latch with 3-STATE Outputs

### General Description

The ACQ/ACTQ573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ( $\overline{OE}$ ) inputs. The ACQ/ACTQ573 is functionally identical to the ACQ/ACTQ373 but with inputs and outputs on opposite sides of the package. The ACQ/ACTQ utilizes Fairchild's Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

### Features

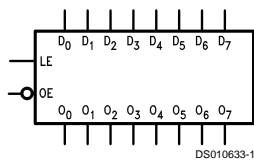
- $I_{CC}$  and  $I_{OZ}$  reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Outputs source/sink 24 mA
- Faster prop delays than standard AC/ACT573
- 4 kV minimum ESD immunity

### Ordering Code:

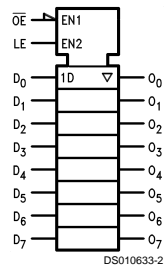
Order Number	Package Number	Package Description
74ACQ573SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package
74ACQ573SJ	M20D	20-Lead (0.300" Wide) Molded Shrink Small Outline Package EIAJ
74ACQ573PC	V20A	20-Lead Molded Dual-in-Line Package
74ACTQ573SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package
74ACTQ573SJ	M20D	20-Lead (0.300" Wide) Molded Shrink Small Outline Package EIAJ
74ACTQ573PC	V20A	20-Lead Molded Dual-in-Line Package
74ACTQ573QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

### Logic Symbols

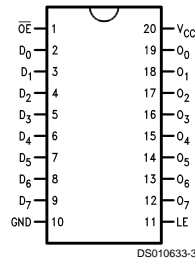


#### IEEE/IEC



### Connection Diagram

#### Pin Assignment for DIP QSOP and SOIC



### Pin Descriptions

Pin Names	Description
$D_0$ – $D_7$	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
$O_0$ – $O_7$	3-STATE Latch Outputs

## Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	$O_n$
L	H	H	H
L	H	L	L
L	L	X	$O_0$
H	X	X	Z

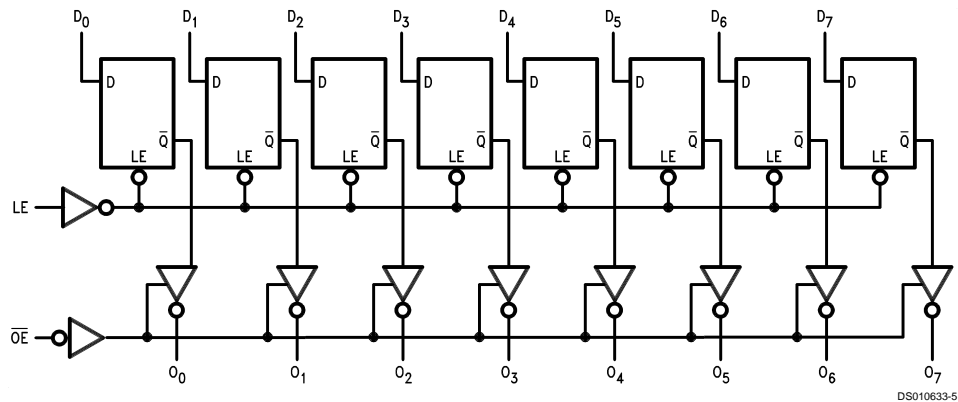
H = HIGH Voltage  
 L = LOW Voltage  
 Z = High Impedance  
 X = Immaterial  
 $O_0$  = Previous  $O_0$  before HIGH-to-LOW transition of Latch Enable

## Functional Description

The ACQ/ACTQ573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the  $D_n$  inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D-type input changes. When LE is LOW the latches store the information that was present on

the D-type inputs at setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ( $\overline{OE}$ ) input. When  $\overline{OE}$  is LOW, the buffers are enabled. When  $\overline{OE}$  is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

## Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

## Absolute Maximum Ratings (Note 1)

Supply Voltage ( $V_{CC}$ )	-0.5V to +7.0V
DC Input Diode Current ( $I_{IK}$ )	
$V_I = -0.5V$	-20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage ( $V_I$ )	-0.5V to $V_{CC} + 0.5V$
DC Output Diode Current ( $I_{OK}$ )	
$V_O = -0.5V$	-20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage ( $V_O$ )	-0.5V to $V_{CC} + 0.5V$
DC Output Source or Sink Current ( $I_O$ )	±50 mA
DC $V_{CC}$ or Ground Current per Output Pin ( $I_{CC}$ or $I_{GND}$ )	±50 mA
Storage Temperature ( $T_{STG}$ )	-65°C to +150°C
DC Latchup Source or Sink Current	±300 mA
Junction Temperature ( $T_J$ )	
PDIP	140°C

## Recommended Operating Conditions

Supply Voltage ( $V_{CC}$ )	
ACQ	2.0V to 6.0V
ACTQ	4.5V to 5.5V
Input Voltage ( $V_I$ )	0V to $V_{CC}$
Output Voltage ( $V_O$ )	0V to $V_{CC}$
Operating Temperature ( $T_A$ )	-40°C to +85°C
Minimum Input Edge Rate $\Delta V/\Delta t$	
ACQ Devices	
$V_{IN}$ from 30% to 70% of $V_{CC}$	
$V_{CC}$ @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate $\Delta V/\Delta t$	
ACTQ Devices	
$V_{IN}$ from 0.8V to 2.0V	
$V_{CC}$ @ 4.5V, 5.5V	125 mV/ns

**Note 1:** Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

## DC Electrical Characteristics for ACQ

Symbol	Parameter	$V_{CC}$ (V)	$T_A = +25^\circ\text{C}$		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	Units	Conditions	
			Typ	Guaranteed Limits				
$V_{IH}$	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$	
		4.5	2.25	3.15	3.15			
		5.5	2.75	3.85	3.85			
$V_{IL}$	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$	
		4.5	2.25	1.35	1.35			
		5.5	2.75	1.65	1.65			
$V_{OH}$	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	$I_{OUT} = -50 \mu\text{A}$	
		4.5	4.49	4.4	4.4			
		5.5	5.49	5.4	5.4			
			3.0		2.56	2.46	V	$V_{IN} = V_{IL}$ or $V_{IH}$ $I_{OH} = -12 \text{ mA}$ $I_{OH} = -24 \text{ mA}$ $I_{OH} = -24 \text{ mA (Note 2)}$
			4.5		3.86	3.76		
			5.5		4.86	4.76		
$V_{OL}$	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	$I_{OUT} = 50 \mu\text{A}$	
		4.5	0.001	0.1	0.1			
		5.5	0.001	0.1	0.1			
			3.0		0.36	0.44	V	$V_{IN} = V_{IL}$ or $V_{IH}$ $I_{OL} = 12 \text{ mA}$ $I_{OL} = 24 \text{ mA}$ $I_{OL} = 24 \text{ mA (Note 2)}$
			4.5		0.36	0.44		
			5.5		0.36	0.44		
$I_{IN}$ (Note 4)	Maximum Input Leakage Current	5.5		± 0.1	± 1.0	μA	$V_I = V_{CC}, \text{ GND}$	
$I_{OLD}$	Minimum Dynamic	5.5			75	mA	$V_{OLD} = 1.65 V_{Max}$	
$I_{OHD}$	Output Current (Note 3)	5.5			-75	mA	$V_{OHD} = 3.85 V_{Min}$	
$I_{CC}$ (Note 4)	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	$V_{IN} = V_{CC}$ or GND	
$I_{OZ}$	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	$V_I (\text{OE}) = V_{IL}, V_{IH}$ $V_I = V_{CC}, \text{ GND}$ $V_O = V_{CC}, \text{ GND}$	
$V_{OLP}$	Quiet Output	5.0	1.1	1.5		V	Figures 1, 2	

## DC Electrical Characteristics for ACQ (Continued)

Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
	Maximum Dynamic V <sub>OL</sub>						(Notes 5, 6)
V <sub>OLV</sub>	Quiet Output	5.0	-0.6	-1.2		V	Figures 1, 2
	Minimum Dynamic V <sub>OL</sub>						(Notes 5, 6)
V <sub>IHD</sub>	Minimum High Level Dynamic Input Voltage	5.0	3.1	3.5		V	(Notes 5, 7)
V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage	5.0	1.9	1.5		V	(Notes 5, 7)

**Note 2:** All outputs loaded; thresholds on input associated with output under test.

**Note 3:** Maximum test duration 2.0 ms, one output loaded at a time.

**Note 4:** I<sub>IN</sub> and I<sub>CC</sub> @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V<sub>CC</sub>.

**Note 5:** Plastic DIP package.

**Note 6:** Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.

**Note 7:** Max number of Data Inputs (n) switching. (n - 1) Inputs switching 0V to 5V (ACQ). Input-under-test switching: 5V to threshold (V<sub>ILD</sub>), 0V to threshold (V<sub>IHD</sub>), f = 1 MHz.

## DC Electrical Characteristics for ACTQ

Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
V <sub>IH</sub>	Minimum High Level	4.5	1.5	2.0	2.0	V	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1V
	Input Voltage	5.5	1.5	2.0	2.0		
V <sub>IL</sub>	Maximum Low Level	4.5	1.5	0.8	0.8	V	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1V
	Input Voltage	5.5	1.5	0.8	0.8		
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4	V	I <sub>OUT</sub> = -50 μA
		5.5	5.49	5.4	5.4		
		4.5		3.86	3.76	V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OH</sub> = -24 mA I <sub>OH</sub> = -24 mA (Note 8)
		5.5		4.86	4.76		
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	V	I <sub>OUT</sub> = 50 μA
		5.5	0.001	0.1	0.1		
		4.5		0.36	0.44	V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OL</sub> = 24 mA I <sub>OL</sub> = 24 mA (Note 8)
		5.5		0.36	0.44		
I <sub>IN</sub>	Maximum Input Leakage Current	5.5		±0.1	±1.0	μA	V <sub>I</sub> = V <sub>CC</sub> , GND
I <sub>OZ</sub>	Maximum 3-STATE Leakage Current	5.5		±0.25	±2.5	μA	V <sub>I</sub> = V <sub>IL</sub> , V <sub>IH</sub> V <sub>O</sub> = V <sub>CC</sub> , GND
I <sub>CCT</sub>	Maximum I <sub>CC</sub> /Input	5.5	0.6		1.5	mA	V <sub>I</sub> = V <sub>CC</sub> - 2.1V
I <sub>OLD</sub>	Minimum Dynamic	5.5			75	mA	V <sub>OLD</sub> = 1.65V Max
I <sub>OHD</sub>	Output Current (Note 9)	5.5			-75	mA	V <sub>OHD</sub> = 3.85V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5		4.0	40.0	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	5.0	1.1	1.5		V	Figures 1, 2 (Notes 10, 11)
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	5.0	-0.6	-1.2		V	Figures 1, 2 (Notes 10, 11)
V <sub>IHD</sub>	Minimum High Level Dynamic Input Voltage	5.0	1.9	2.2		V	(Notes 10, 12)

## DC Electrical Characteristics for ACTQ (Continued)

Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Notes 10, 12)

**Note 8:** All outputs loaded; thresholds on input associated with output under test.

**Note 9:** Maximum test duration 2.0 ms, one output loaded at a time.

**Note 10:** Plastic DIP package.

**Note 11:** Max number of outputs defined as (n). Data Inputs are driven 0V to 3V. One output @ GND.

**Note 12:** Max number of data inputs (n) switching. (n - 1) inputs switching 0V to 3V (ACTQ). Input-under-test switching: 3V to threshold (V<sub>ILD</sub>), 0V to threshold (V<sub>IHD</sub>). f = 1 MHz.

## AC Electrical Characteristics for ACQ

Symbol	Parameter	V <sub>CC</sub> (V) (Note 13)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF			T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Units
			Min	Typ	Max	Min	Max	
t <sub>PHL</sub>	Propagation Delay	3.3	2.5	8.5	10.5	2.5	11.0	ns
t <sub>PLH</sub>	D <sub>n</sub> to O <sub>n</sub>	5.0	1.5	5.5	7.0	1.5	7.5	
t <sub>PLH</sub>	Propagation Delay	3.3	2.5	8.5	12.0	2.5	12.5	ns
t <sub>PHL</sub>	LE to O <sub>n</sub>	5.0	2.0	6.0	8.0	2.0	8.5	
t <sub>PZL</sub>	Output Enable Time	3.3	2.5	8.5	13.0	2.5	13.5	ns
t <sub>PZH</sub>		5.0	1.5	6.0	8.5	1.5	9.0	
t <sub>PHZ</sub>	Output Disable Time	3.3	1.0	9.0	14.5	1.0	15.0	ns
t <sub>PLZ</sub>		5.0	1.0	6.0	9.5	1.0	10.0	
t <sub>OSHL</sub>	Output to Output Skew (Note 14)	3.3		1.0	1.5		1.5	ns
t <sub>OSLH</sub>	D <sub>n</sub> to O <sub>n</sub>	5.0		0.5	1.0		1.0	

**Note 13:** Voltage Range 5.0 is 5.0V ±0.5V

Voltage Range 3.3 is 3.3V ±0.3V

**Note 14:** Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t<sub>OSHL</sub>) or LOW to HIGH (t<sub>OSLH</sub>). Parameter guaranteed by design.

## AC Operating Requirements

Symbol	Parameter	V <sub>CC</sub> (V) (Note 15)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF		T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Units
			Typ	Guaranteed Minimum			
t <sub>S</sub>	Setup Time, HIGH or LOW	3.3	0	3.0		3.0	ns
	D <sub>n</sub> to LE	5.0	0	3.0		3.0	
t <sub>H</sub>	Hold Time, HIGH or LOW	3.3	0	1.5		1.5	ns
	D <sub>n</sub> to LE	5.0	0	1.5		1.5	
t <sub>W</sub>	LE Pulse Width, HIGH	3.3	2.0	4.0		4.0	ns
		5.0	2.0	4.0		4.0	

**Note 15:** Voltage Range 5.0 is 5.0V ±0.5V

Voltage Range 3.3 is 3.3V ±0.3V

## AC Electrical Characteristics for ACTQ

Symbol	Parameter	V <sub>CC</sub> (V) (Note 16)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF			T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Units
			Min	Typ	Max	Min	Max	
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation Delay D <sub>n</sub> to O <sub>n</sub>	5.0	2.0	6.5	7.5	2.0	8.0	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay LE to O <sub>n</sub>	5.0	2.5	7.0	8.5	2.5	9.0	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Output Enable Time	5.0	2.0	7.0	9.0	2.0	9.5	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Output Disable Time	5.0	1.0	8.0	10.0	1.0	10.5	ns
t <sub>OSHL</sub> t <sub>OSLH</sub>	Output to Output Skew (Note 17) D <sub>n</sub> to O <sub>n</sub>	5.0		0.5	1.0		1.0	ns

**Note 16:** Voltage Range 5.0 is 5.0V ±0.5V

**Note 17:** Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t<sub>OSHL</sub>) or LOW to HIGH (t<sub>OSLH</sub>). Parameter guaranteed by design.

## AC Operating Requirements for ACTQ

Symbol	Parameter	V <sub>CC</sub> (V) (Note 18)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF		T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Units
			Typ	Guaranteed Minimum			
t <sub>S</sub>	Setup Time, HIGH or LOW D <sub>n</sub> to LE	5.0	0	3.0	3.0		ns
t <sub>H</sub>	Hold Time, HIGH or LOW D <sub>n</sub> to LE	5.0	0	1.5	1.5		ns
t <sub>W</sub>	LE Pulse Width, HIGH	5.0	2.0	4.0	4.0		ns

**Note 18:** Voltage Range 5.0 is 5.0V ±0.5V

## Capacitance

Symbol	Parameter	Typ	Units	Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = OPEN
C <sub>PD</sub>	Power Dissipation Capacitance	42.0	pF	V <sub>CC</sub> = 5.0V

## FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator  
PC-163A Test Fixture  
Tektronics Model 7854 Oscilloscope

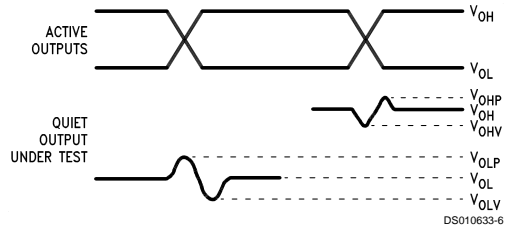
Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before

testing. This will ensure that the outputs switch simultaneously.

3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.
5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

## FACT Noise Characteristics (Continued)



**Note 19:**  $V_{OHV}$  and  $V_{OLP}$  are measured with respect to ground reference.

**Note 20:** Input pulses have the following characteristics:  $f = 1$  MHz,  $t_r = 3$  ns,  $t_f = 3$  ns, skew  $< 150$  ps.

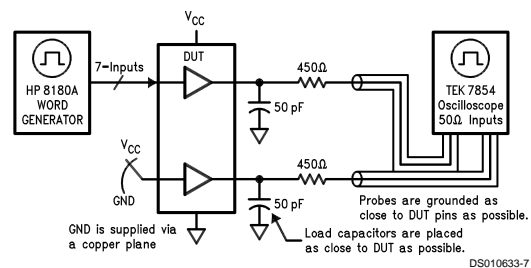
**FIGURE 1. Quiet Output Noise Voltage Waveforms**

$V_{OLP}/V_{OLV}$  and  $V_{OHP}/V_{OHV}$ :

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50 $\Omega$  coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure  $V_{OLP}$  and  $V_{OLV}$  on the quiet output during the worst case transition for active and enable. Measure  $V_{OHP}$  and  $V_{OHV}$  on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

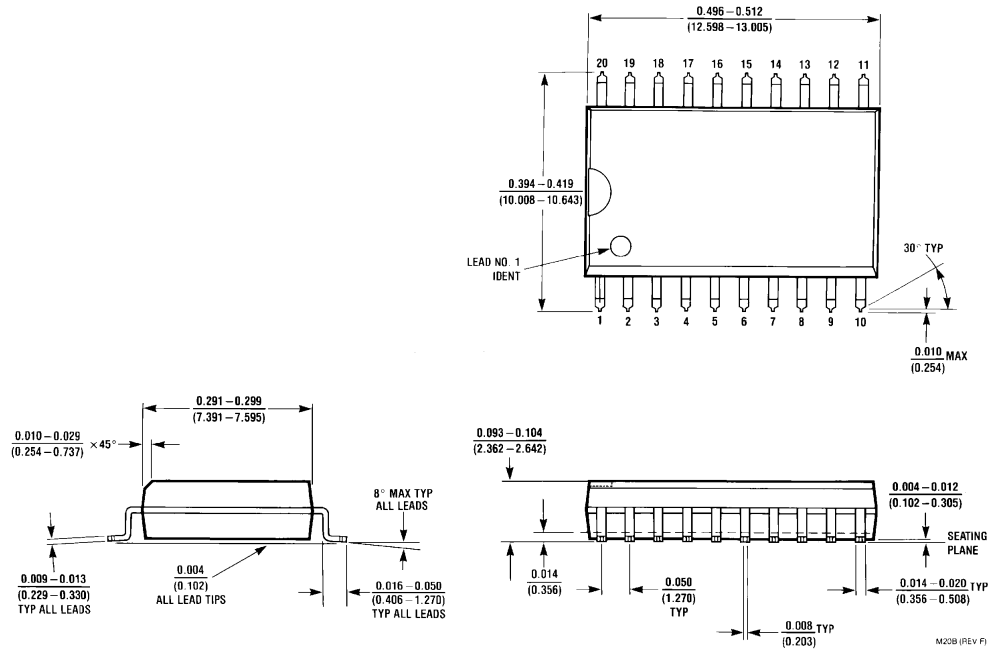
$V_{ILD}$  and  $V_{IHD}$ :

- Monitor one of the switching outputs using a 50 $\Omega$  coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level,  $V_{IL}$ , until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds  $V_{IL}$  limits, or on output HIGH levels that exceed  $V_{IH}$  limits. The input LOW voltage level at which oscillation occurs is defined as  $V_{ILD}$ .
- Next decrease the input HIGH voltage level,  $V_{IH}$ , until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds  $V_{IL}$  limits, or on output HIGH levels that exceed  $V_{IH}$  limits. The input HIGH voltage level at which oscillation occurs is defined as  $V_{IHD}$ .
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

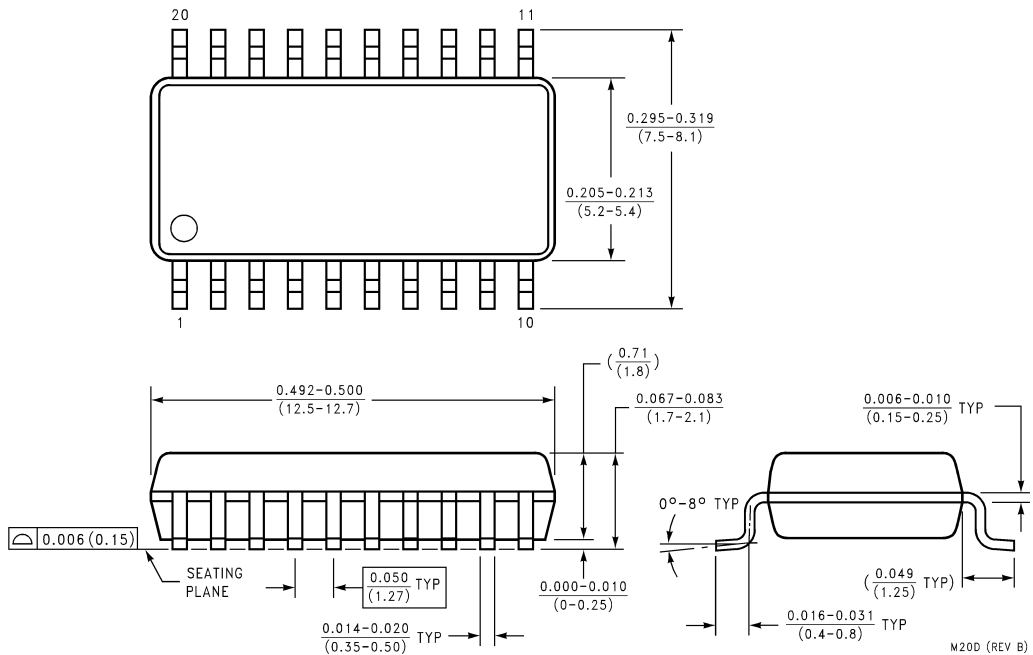


**FIGURE 2. Simultaneous Switching Test Circuit**

**Physical Dimensions** inches (millimeters) unless otherwise noted



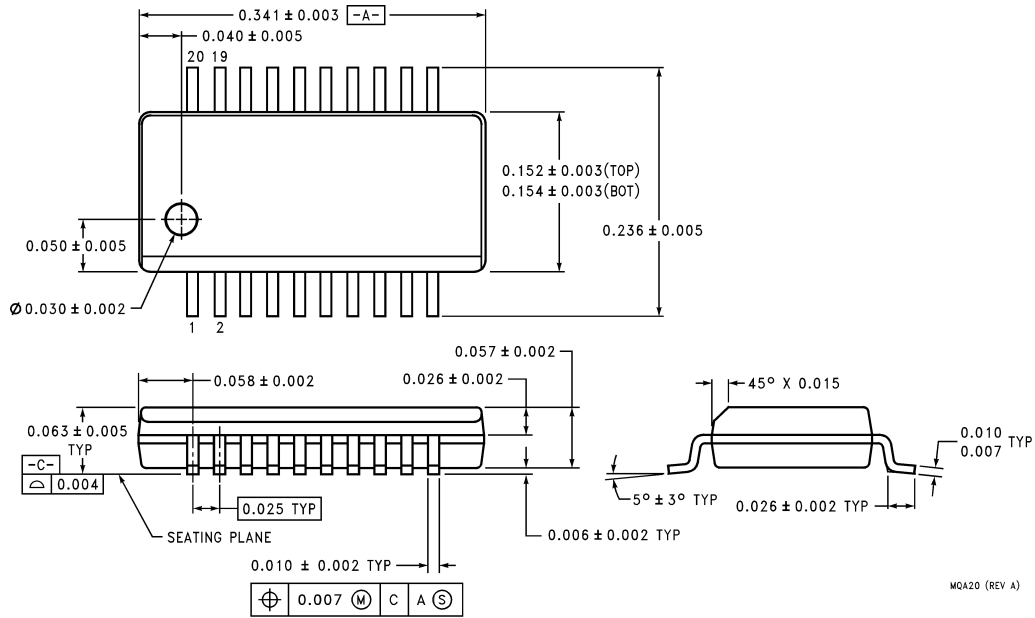
**20-Lead (0.300" Wide) Molded Small Outline Package  
Package Number M20B**



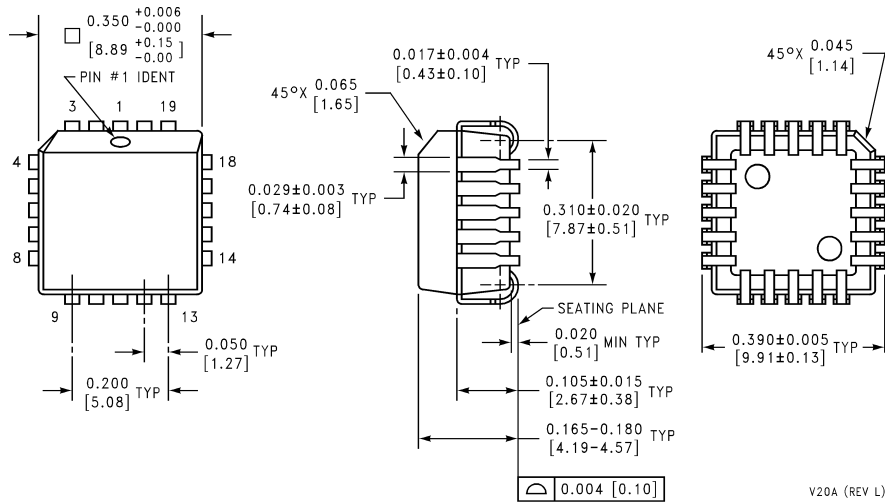
**20-Lead (0.300" Wide) Molded Shrink Small Outline Package EIAJ  
Package Number M20D**



**Physical Dimensions** inches (millimeters) unless otherwise noted (Continued)



**20-Lead (0.150" Wide) Molded Shrink Small Outline Package**  
**Package Number MQA20**



**20-Lead Molded Dual-in-Line Package**  
**Package Number V20A**

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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